

SBR1620 THRU SBR16100

CURRENT 16.0Amperes
VOLTAGE 20 to 100 Volts

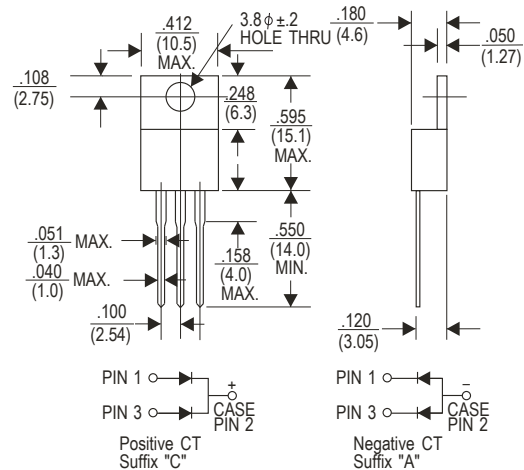
Features

- Plastic Package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction, majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss, high efficiency
- High current capability, Low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- Dual rectifier construction
- High temperature soldering guaranteed : 250°C/10 seconds, 0.25" (6.35mm) from case

Mechanical Data

- Case : JEDEC TO-220 molded plastic body
- Terminals : Lead solderable per MIL-STD-750, Method 2026
- Polarity : As marked. No suffix indicates Common Cathode, suffix "A" indicates Common Anode
- Mounting Position : Any
- Weight : 0.08 ounce, 2.24 grams

TO-220



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

(Ratings at 25°C ambient temperature unless otherwise specified, single phase, half wave, resistive or inductive load. For capacitive load, derate by 20%)

	Symbols	SBR 1620	SBR 1630	SBR 1640	SBR 1650	SBR 1660	SBR 1680	SBR 16100	Units
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	80	100	Volts
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	56	70	Volts
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	80	100	Volts
Maximum average forward rectified current at T _c =95°C	I _(AV)	16.0							Amps
Repetitive peak forward current(square wavr, 20KHZ) at T _c =105°C	I _{FRM}	32.0							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}	150.0							Amps
Maximum instantaneous forward voltage at 8.0A (Note 1)	V _F	0.65		0.75		0.80	0.85	Volts	
Maximum instantaneous reverse current at rated DC blocking voltage (Note1)	I _R	T _A =25°C	1.0						mA
		T _A =125°C	30		50				
Typical thermal resistance (Note 2)	R _{θJC}	3.0							°C/W
Operating junction temperature range	T _J	-65 to +125			-65 to +150				°C
Storage temperature range	T _{STG}	-65 to +150							°C

Notes:

- (1) Pulse test: 300μS pulse width, 1% duty cycle
- (2) Thermal resistance from junction to case



RATINGS AND CHARACTERISTIC CURVES SBR1620-SBR16100

FIG.1-FORWARD CURRENT DERATING CURVE

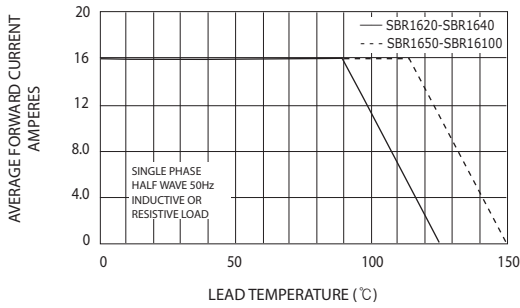


FIG.2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

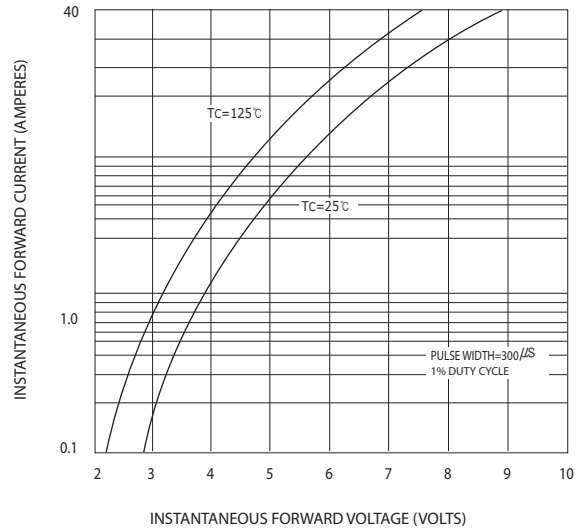


FIG.4-TYPICAL JUNCTION CAPACITANCE

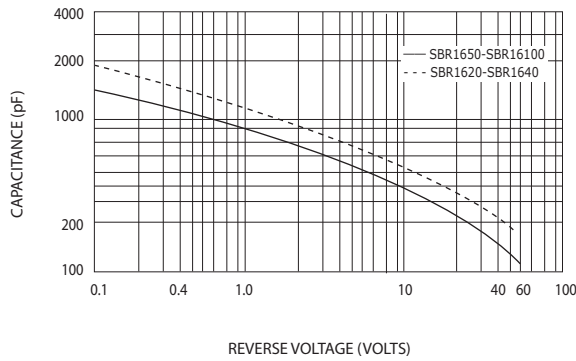


FIG.3-TYPICAL REVERSE CHARACTERISTICS

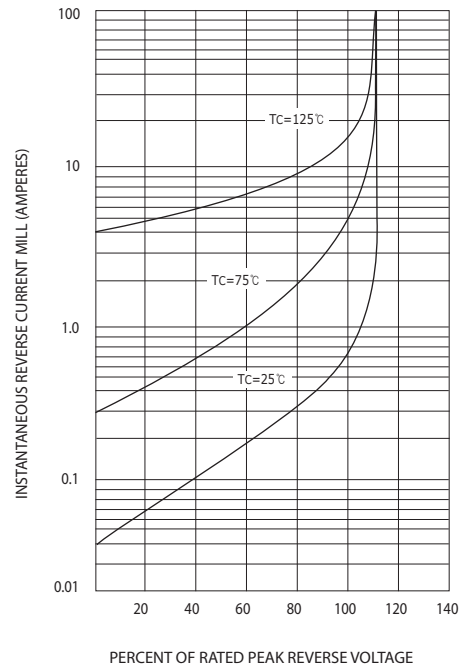


FIG.5-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

